and the selection is triggered by subtle changes in the nature of the incoming silane. [2] Furthermore, selective isotope exchange in osmium and ruthenium silyl complexes suggests that the CH-activation stage of Equation (1) is also reversible. [3] Recent reports of the direct observation of aliphatic β -C-H bond elimination in 16-electron metal silyl complexes by us and by Klei et al. [4] conclusively establish the reversibility of C-H addition/elimination processes in some metal silyl complexes [Eq. (1)]. We now report the first example of conversion from [M]SiMe₃ to β -agostic [M]CH₂SiMe₂-H species, a total inversion of the usual left-to-right direction of the process in Equation (1).

Treatment of a mixture of the 16-electron $[(Me_3P)_3Ru-(SiMe_3)H]$, in equilibrium with the "silene dihydride" complex $[(Me_3P)_3Ru(\eta^2-CH_2SiMe_2)(H)_2]$ (1)^[4a,b] with CHCl₃ between -40 and 0°C leads to the chlorination of one hydride and the formation of $[(Me_3P)_3Ru(CH_2SiMe_2)(H)Cl]$, fac-(2) [Eq. (2)], which has been isolated in 86% yield and

Agostic Si-H Interactions

Tandem β-C-H Activation/Si-H Elimination Reactions: Stabilization of C-H Activation Products by β-Agostic Si-H Interactions**

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Organometallic complexes of silenes have been postulated and often observed to be intermediates in many C–H, Si–H, Si–C, and Si–Si bond-breaking and bond-forming processes. Many isolated and characterized silene complexes have been synthesized via β -Si–H activation of CH $_2$ SiR $_2$ -H ligands, but this reaction often proceeds further to furnish the metal silyl (MSiR $_2$ CH $_3$) as a more thermodynamically stable product [Eq. (1)]. $^{[1a]}$ Interestingly, this preference of breaking SiH/MC

and forming CH/MSi bonds is not universal. For instance, the silene complex $[(\eta^5\text{-}C_5Me_5)Ru(PiPr_3)(\eta^2\text{-}CH_2SiPh_2)H],$ formed via $\beta\text{-}Si\text{--}H$ activation, in some cases reacts with hydrosilanes via Si-H instead of C-H reductive elimination,

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$$P_{M_{N_{N}}} = PMe_{3}$$

$$H_{2}C = PMe_{3}$$

$$H_{3}C = PMe_{3}$$

$$H_{2}C = PMe_{3}$$

$$H_{3}C = PMe_{3}$$

$$H_{3}C = PMe_{3}$$

$$H_{3}C = PMe_{3}$$

$$H_{4}C = PMe_{4}$$

$$H_{4$$

fully characterized. That this complex is neither a simple η^2 -silene hydride nor a η^1 -alkyl is evident from strong Si–H scalar coupling $(J(H,Si)=75 \text{ Hz}).^{[5]}$ A very weak, low-frequency band in the IR spectrum (1615 cm⁻¹; absent in [D₁] fac-2) is also consistent with an agostic Si···H···Ru, but this assignment is tentative because of the very low intensity of the band.

A more convenient synthetic route to *fac-2* is based on *cis*-[(Me₃P)₄Ru(CH₂SiMe₂Cl)H] (3), which in turn can be readily synthesized from [(Me₃P)₄Ru(SiMe₃)H] and HSiMe₂CH₂Cl [Eq. (3)]. Isotopically labeled material, [D₁]*fac-2* was synthe-

$$P_{M_{1}} = P_{M_{2}} = P_{M_{3}} = P_{M_{1}} = P_{M_{2}} = P_{M_{3}} = P_{M_{4}} = P_{M_{5}} = P_{M$$

sized using DSiMe₂CH₂Cl. Note that the deuterium atom is only found as Si-D-Ru and no scrambling into C–H positions was observed. The structure of **3** was determined by single-crystal X-ray diffraction to be approximately octahedral, with all bond distances and angles within normal ranges. No evidence for nonclassical Si–Cl···Ru, Si···H–Ru, or Ru–H····Cl interactions was observed in the solid state or in solution

Zuschriften

(¹H NMR: J(H,Si) < 12 Hz; IR: \tilde{v} (RuH) = 1840 cm⁻¹; Si···H 3.34; Cl···Ru 4.86; H···Cl 4.54 Å).

Thermal (65 °C) or photochemical (350 nm) treatment of 3 in hydrocarbon solvents leads to phosphane loss and formation of fac-2. Under thermal conditions, fac-2 is in equilibrium with 3, although the product is strongly favored $(K_{eq} \approx 0.06 \text{ mol L}^{-1} \text{ at } 25 \,^{\circ}\text{C})$. Removal of PMe₃ and addition of fresh solvent allows the isolation of 2 nearly quantitatively. In addition, approximately 5% of the meridional isomer mer-(2) is also observed [Eq. (3)]. The structure of mer-2 was determined from a pure sample obtained by fractional crystallization (see below). The spectroscopic data is also consistent with the meridional structure, and again, a strong SiH scalar coupling (J(H,Si) = 77.5 Hz) indicates a nonclassical Ru···H···Si linkage.^[5] The formation of 3 from HSi-Me₂CH₂Cl and [(Me₃P)₄Ru(SiMe₃)H] and the subsequent conversion of 3 to 2 is an interesting sequence of reactions. Initial exchange of silyl ligands on the metal center by SiH addition and Me₃SiH elimination seems likely, given that Me₃SiCH₂Cl, which lacks the SiH group, does not react after days at ambient temperature. The migration of the chloride ion from carbon to silicon in the synthesis of 3 may involve a dyotropic process as suggested in a similar case for [CpFe-(CO)₂(SiMe₂CH₂Cl)].^[6] An alternative mechanism involving the oxidative addition of C-Cl and the elimination of Si-Cl cannot be completely excluded, however the intermediate would have to be a yet unknown isomer of 2, as neither fac-2 nor mer-2 favor the recoordination of PMe₃ and the formation of 3.

The rate of conversion of **3** to **2** is approximately halved in the presence of added $[D_9]PMe_3$ (10 equiv), and the labeled phosphane is nonselectively incorporated into both **3** and **2**. This suggests the reaction proceeds via initial PMe_3 dissociation, and SiCl oxidative addition would be a likely second step. Interestingly, there are relatively few clear precedents for the oxidative addition of SiCl. ^[7] It is also noteworthy that the strong Si–Cl bond is maintained in **3**, but cleaved in **2** in preference for Ru–Cl (and agostic Si···H) bonds. It is likely that Cl–Ru π -donation compensates for partial electronic unsaturation in **2**, whereas additional electron donation would contribute nothing to the stability of **3**, an unequivocally 18-electron species.

The solid-state structures of fac-2 and mer-2 can both be described as square pyramidal, with three phosphane groups, a Cl atom, and the CH₂ group positioned around the ruthenium center, and the agostic Si-H occupying a sixth coordination site (Figure 1 and 2). Disorder of the agostic {CSiH} fragment in fac-2 was successfully modeled (see Experimental Section), and while the heavy-atom positions should be reliable, the location of the hydride is less precise than usual. The Ru-P, Ru-Cl, and Ru-C bond lengths and angles are within normal ranges, but the Ru-Si bond lengths (fac-2: 2.526(2); mer-2: 2.468(2) Å) are at the long end of the range for Ru-Si single bonds (approximately 2.3-2.58 Å; 2.39 Å on average). [8] Longer Ru-C and Ru-Si separations in fac-2 than in the mer isomer may be due the stronger trans influence of phosphane versus Cl on the agostic CSiH ligand, but the crystallographic disorder may also contribute. The hydrides in fac-2 and mer-2 were located in positions bridging

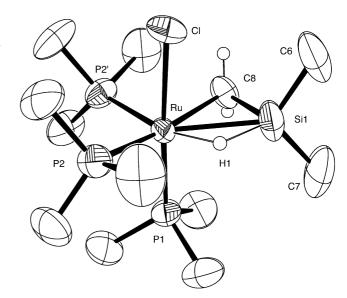


Figure 1. ORTEP diagram of complex fac-2 (30% probability ellipsoids). The second disordered position of the silene fragment is not shown. Selected bond lengths [Å] and angles [°]: Ru-C8 2.307(7), Ru-Si1 2.526(2), Si-C6 1.837(9), Si-C7 1.814(9), Si-C8 1.788(11), Ru-H1 1.550, Si-H1 1.664; Si1-C8-Ru 75.0(3), C8-Si1-Ru 61.9(2).

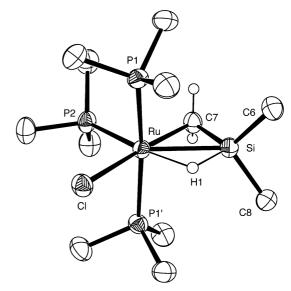


Figure 2. ORTEP diagram of complex mer-2 (30% probability ellipsoids). Selected bond lengths [Å] and angles [°]: Ru-C7 2.200(6), Ru-Si 2.468(2), Si-C6 1.878(4), Si-C7 1.790(6), Ru-H1 1.732, Si-H1 1.557; Si-C7-Ru 75.7(2), C7-Si-Ru 59.7(2).

the silicon and ruthenium centers (Ru···H/Si···H = 1.550/1.664 Å in *fac-*2 and 1.732/1.557 Å in *mer-*2), consistent with agostic interactions indicated by the spectroscopic evidence. Silane σ -bond complexes can be viewed as products of "arrested" Si–H elimination on the pathway from metal-(silyl)(hydride) complexes to silanes. Analogously, *fac-* and *mer-*2 can be considered as being frozen during the intramolecular β -Si–H elimination from the ruthenium silene hydride complexes. The Si–C distances (*fac-*2: 1.788(11); *mer-*2: 1.790(6) Å) are shorter than normal Si–C single bonds (approximately 1.87–1.91 Å), [8] but are comparable to those in

metal silene complexes (1.78-1.81 Å).^[9] However, the Ru-Si bond lengths in both fac- and mer-2 are much longer than in known silene complexes. [9a,b] On the other hand, short Si-C distances are also observed in ruthenium complexes reported by Jones and co-workers ([Cp*(Cy₃P)Ru{η³-HSiMe₂- $(C=CPh_2)$], [5a]) and Sabo-Etienne and co-workers $([(Cy_{3}P)_{2}RuH_{2}\{\eta^{4}\text{-}HSiMe_{2}(CH\!\!=\!\!CHMe)\}]).^{[5b]}\ \, These\ \, \beta\text{-}agos$ tic RuCSiH species also exhibit long Ru-Si and short Si-H bond lengths and can be viewed as an arrested stage of the reductive elimination from 1-silaallene and η^3 -silaallyl complexes. Comparison with these compounds strongly supports the view that fac- and mer-2 are better described as β -agostic rather than silene complexes. It is tempting to attribute the relative stability of the β -agostic motif entirely to the influence of chloride in 2, but structural data is not available for 1. Furthermore, spectroscopic evidence for 1 is consistent with some degree of Si...H interaction. Studies probing the similarities and differences in the structures of 1, 2, and substituted derivatives are currently in progress.

The reaction proceeding from [(Me₃P)₃Ru(H)SiMe₃] to **1** and further on to *fac*- and *mer*-**2** is the first example of a [M]SiMe₃ to β-agostic [M]CH₂SiMe₂-H conversion, a reversal of the typical sequence observed in the rearrangement of silaalkyl metal complexes. This reversal is likely the result of SiH coordination to the unsaturated metal center, which would provide greater stabilization than any potential agostic C–H binding in the metal silyl.

Experimental Section

Synthetic procedures and characterization data are included in the Supporting Information.

fac-2: $0.32 \times 0.30 \times 0.24$ mm; orthorhombic; Pnma (no. 62); a = 18.7076(3), b = 10.6471(2), c = 10.5218(2) Å, V = 2095.75(7) Å³, Z = 4, $\rho_{\rm calcd} = 1.388$ g cm⁻³; $2\theta_{\rm max} = 50.7^{\circ}$; Mo_{Kα} radiation ($\lambda = 0.71069$ Å); \varnothing oscillations (Rigaku R-AXIS IIc); T = 200 K; 12.712 reflections, all 2027 unique reflections were used in the refinement; corrected for Lorentz and polarization effects but not for absorption ($\mu = 11.79$ cm⁻¹); solution by direct methods (SIR92); refinement by full-matrix least-squares based on F^2 (SHELXL-93); 137 parameters; hydrogen atoms unrefined (H1 was located); $R_1 = 0.0379$ and $wR_2 = 0.0991$ for 1962 reflections for which $I > 2\sigma(I)$; residual electron density +0.492 and -0.527 eÅ⁻³; the molecule lies on a crystallographic mirror plane perpendicular to the Ru-C8-Si-H1 plane (disordered Si and C8 refined successfully at 50% occupancy). One PMe₃ (P2) was rotationally disordered about the Ru-P2 bond (55:45 relative populations).

mer-2: $0.44 \times 0.22 \times 0.12$ mm; orthorhombic; $Cmc2_1$ (no. 36); a = 16.2940(4), b = 10.9748(2), c = 11.4191(3) Å, V = 2042.00(8) Å³, Z = 10.4191(3) Å, V = 10.4191(3) Å,

4, $\rho_{\rm calcd}=1.424~{\rm g\,cm^{-3}}$; $2\theta_{\rm max}=54.96^{\circ}$; ${\rm Mo_{K\alpha}}$ radiation ($\lambda=0.71069~{\rm \AA}$); \varnothing oscillations (Rigaku R-AXIS IIc); $T=200~{\rm K}$; 8222 reflections, all 2173 unique reflections were used in the refinement; absorption correction by REQAB ($\mu=11.79~{\rm cm^{-1}}$, min./max. transmission 0.693/1.000); solution by direct methods (SIR92); refinement by full-matrix least-squares based on F^2 (SHELXL-93); 97 parameters; hydrogen atoms unrefined (H1, H5a, H5b, and H7a were located); $R_1=0.0358$ and $wR_2=0.0929$ for 2144 reflections for which $I>2\sigma(I)$; residual electron density +0.814 and $-0.855~{\rm e\,\AA^{-3}}$.

CCDC-166039 (fac-2), CCDC-166037 (mer-2), and CCDC-166038 (3) contain the supplementary crystallographic data for this paper. These data can be obtained free of charge via www.ccdc.cam.ac.uk/conts/retrieving.html (or from the Cambridge Crystallographic Data Centre, 12, Union Road, Cambridge CB21EZ, UK; fax: (+44)1223-336-033; or deposit@ccdc.cam.ac.uk).

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